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April 1st, 2010 Renesas Electronics Corporation

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silicon power transistor 2SC4332,4332-Z

PACKAGE DRAWINGS (Unit: mm)

NPN SILICON EPITAXIAL TRANSISTOR FOR HIGH-SPEED SWITCHING

v

v

v

А

A

A W

w

°C

°C

The 2SC4332 and 2SC4332-Z are mold power transistors developed for high-speed switching and feature a very low collector-to-emitter saturation voltage.

This transistor is ideal for use in switching regulators, DC/DC converters, motor drivers, solenoid drivers, and other low-voltage power supply devices, as well as for high-current switching.

FEATURES

- Low collector saturation voltage V_{CE(sat)} = 0.3 V MAX. (Ic = 3.0 A / IB = 0.15 A)
- Fast switching speed:
 t_f ≤ 0.3 μs MAX. (Ic = 3.0 A)
- High DC current gain

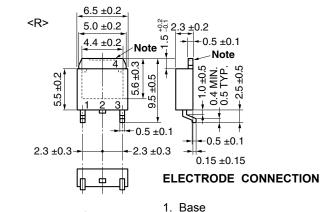
ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Collector to Base Voltage	Vсво	100
Collector to Emitter Voltage	VCEO	60
Base to Emitter Voltage	Vebo	7.0
Collector Current (DC)	IC(DC)	5.0
Collector Current (pulse)	C(pulse) ^{Note1}	10
Base Current (DC)	B(DC)	2.5
Total Power Dissipation	P⊤ (Tc = 25°C)	15
Total Power Dissipation	P⊤ (T _A = 25°C)	1.0 ^{Note2} , 2.0 ^{Note3}
Junction Temperature	Tj	150
Storage Temperature	Tstg	–55 to +150

- **Notes 1.** $PW \le 10 \text{ ms}$, duty cycle $\le 50\%$
 - 2. Printing board mounted
 - **3.** 7.5 cm² x 0.7 mm, ceramic board mounted

6.5 ±0.2 2.3 ±0.2 0.10 'n 5.0 ± 0.2 0.5 ±0.1 4 ±0.2 ģ 1.0 ŝ NIN ഹ 13.7 ШN 1.1 ± 0.2 0.7 0.5 +0.2 0.5 +0.2 .32.3 ö ¢ ф





- TO-252 (MP-3Z)
 - Collector
 Emitter
 - 4. Collector Fin

Note The depth of notch at the top of the fin is from 0 to 0.2 mm.

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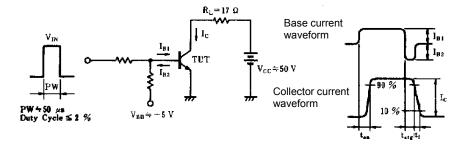
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector to Emitter Voltage	VCEO(SUS)	Ic = 3.0 A, I _B = 0.3 A, L = 1 mH	60			V
Collector to Emitter Voltage	VCEX(SUS)	Ic = 3.0 A, I _{B1} = $-I_{B2}$ = 0.3 A, V _{BE(OFF)} = -1.5 V, L = 180 μ H, clamped	60			V
Collector Cut-off Current	Ісво	Vce = 60 V, Ie = 0			10	μA
Collector Cut-off Current	ICER	$V_{CE} = 60 \text{ V}, \text{R}_{\text{BE}} = 51 \Omega, \text{T}_{\text{A}} = 125^{\circ}\text{C}$			1.0	mA
Collector Cut-off Current	ICEX1	$V_{\text{CE}} = 60 \text{ V}, V_{\text{BE(OFF)}} = -1.5 \text{ V}$			10	μA
Collector Cut-off Current	ICEX2	$\label{eq:Vce} \begin{array}{l} V_{\text{CE}} = 60 \ V, \ V_{\text{BE(OFF)}} = -1.5 \ V, \\ T_{\text{A}} = 125^{\circ}\text{C} \end{array}$			1.0	mA
Emitter Cut-off Current	Іево	V _{EB} = 5.0 V, I _C = 0			10	μA
DC Current Gain	hFE1 ^{Note}	Vce = 2.0 V, Ic = 0.5 A	100			
DC Current Gain	hFE2 ^{Note}	Vce = 2.0 V, Ic = 1.0 A	100		400	
DC Current Gain	hfe3 ^{Note}	Vce = 2.0 V, Ic = 3.0 A	60			
Collector Saturation Voltage	VCE(sat)1 ^{Note}	Ic = 3.0 A, Iв = 0.15 A			0.3	V
Collector Saturation Voltage	VCE(sat)2 ^{Note}	Ic = 4.0 A, I _B = 0.2 A			0.5	V
Base Saturation Voltage	VBE(sat)1 Note	Ic = 3.0 A, I _B = 0.15 A			1.2	V
Base Saturation Voltage	VBE(sat)2	Ic = 4.0 A, I _B = 0.2 A			1.5	V
Collector Capacitance	Cob	$V_{CB} = 10 \text{ V}, I_E = 0, f = 1.0 \text{ MHz}$		130		pF
Gain Bandwidth Product	fт	$V_{CE} = 10 \text{ V}, \text{ Ie} = -0.5 \text{ A}$		150		MHz
Turn-on Time	ton	$I_{C} = 3.0 \text{ A}, \text{ R}_{L} = 16.7 \Omega,$			0.3	μs
Storage Time	tstg	$I_{B1} = -I_{B2} = 0.15 \text{ A}, \text{ Vcc} = 50 \text{ V}$ Refer to the test circuit.			1.5	μs
Fall Time	tr				0.3	μs

Note Pulse test PW \leq 350 μ s, duty cycle \leq 2%

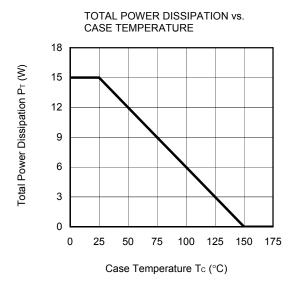
hfe CLASSIFICATION

Marking	М	L	К
hfe2	100 to 200	150 to 300	200 to 400

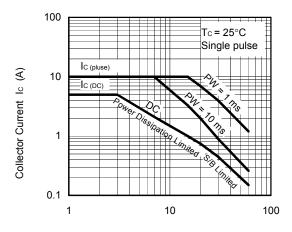
SWITCHING TIME (ton, tstg, tf) TEST CIRCUIT



TYPICAL CHARACTERISTICS (TA = 25°C)

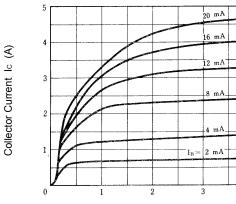


FORWARD BIAS SAFE OPERATING AREA

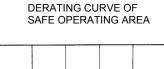


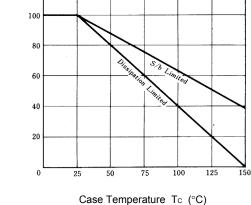
Collector to Emitter Voltage V_{CE} (V)





Collector to Emitter Voltage V_{CE} (V)



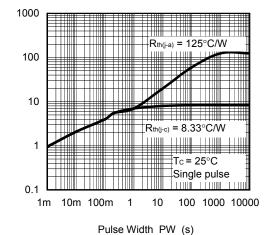


Ic Derating dT (%)

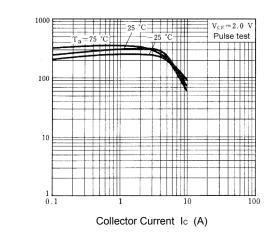
Transient Thermal Resistance rth(J-c) (°C/W)

DC Current Gain h_⊞

TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH

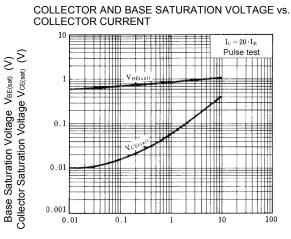


DC CURRENT GAIN vs. COLLECTOR CURRENT



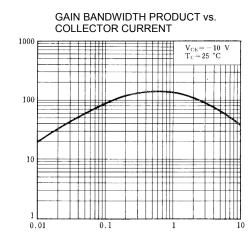
Data Sheet D16430EJ3V0DS

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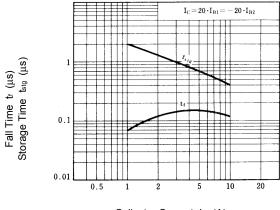
COLLECTOR TO BASE VOLTAGE



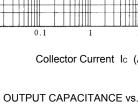
Gain Bandwidth Product fr (MHz)

Collector Current Ic (A)

STORAGE TIME AND FALL TIME vs. COLLECTOR CURRENT



Collector Current Ic (A)



1000 $I_E = 0$ f=1.0 MHz Collector Capacitance Cob (pF) 100 10 10 100 0.1 1 Collector to Base Voltage VCB (V)

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